## NSN 5962-01-014-0500

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View Online at https://aerobasegroup.com/nsn/5962-01-014-0500

Body Length:
Between 1.200 inches and 1.290 inches
Body Width:
Between 0.515 inches and 0.580 inches
Body Height:
Between 0.050 inches and 0.230 inches
Maximum Power Dissipation Rating:
360.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and medium power and medium speed and synchronous and w/clear and edg
triggered
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
-0-015-aa joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
26.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output and 35.00 nanoseconds.
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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N/a

**Terminal Type And Quantity:** 

24 printed circuit Shelf Life:

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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